

www.vishay.com

Vishay Semiconductors

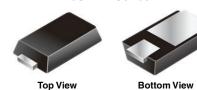
COMPLIANT

HALOGEN

FREE

Ultrafast Rectifier, 2 A FRED Pt®

eSMP® Series



MicroSMP (DO-219AD)

Anode O Cathode

LINKS TO ADDITIONAL RESOURCES



PRIMARY CHARACTERISTICS				
I _{F(AV)}	2 A			
V_{R}	100 V, 200 V			
V _F at I _F	0.82 V			
t _{rr} (typ.)	33 ns			
I _{FSM}	30 A			
T _J max.	175 °C			
Package	MicroSMP (DO-219AD)			
Circuit configuration	Single			

FEATURES

- Very low profile typical height of 1.0 mm
- · Ideal for automated placement
- Low forward voltage drop, low power losses
- Low leakage current
- Meets MSL level 1, per J-STD-020, LF maximum peak of 260 °C
- For PFC, CRM snubber operation
- Material categorization: for definitions of compliance please see www.vishay.com/doc?99912

TYPICAL APPLICATION

For use in high frequency, freewheeling, DC/DC converters, PFC, and in snubber industrial and automotive applications.

MECHANICAL DATA

Case: MicroSMP (DO-219AD)

Molding compound meets UL 94 V-0 flammability rating

Terminals: matte tin plated leads, solderable per

J-STD-002, meets JESD 201 class 2 whisker test

Polarity: color band denotes cathode end

ABSOLUTE MAXIMUM RATINGS					
PARAMETER		SYMBOL	TEST CONDITIONS	VALUES	UNITS
Peak repetitive reverse	VS-2EQH01-M3	V		100	V
voltage	VS-2EQH02-M3	V_{RRM}		200	
Average rectified forward current		I _{F(AV)}	T _M = 137 °C	2	۸
Non-repetitive peak surge current		I _{FSM}	T _J = 25 °C, 10 ms sine pulse	30	А
Operating junction and st	orage temperatures	T _J , T _{Stg}		-55 to +175	°C

ELECTRICAL SPECIFICATIONS (T _J = 25 °C unless otherwise specified)							
PARAMETER		SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS
Breakdown voltage,	VS-2EQH01-M3	V_{BR} ,	L = 100 uA	100	-	-	
blocking voltage	VS-2EQH02-M3	V_{R}^{BH} , $I_{R} = 100 \mu\text{A}$		200			V
Forward voltage		W	I _F = 2 A	-	0.96	1.05	V
Forward voltage		V_{F}	I _F = 2 A, T _J = 150 °C	-	0.82	0.84	
Reverse leakage current		I _R	$V_R = V_R$ rated	-	-	1	
			T _J = 150 °C, V _R = V _R rated	-	-	25	μA
Junction capacitance		C _T	V _R = 200 V	-	6	-	pF

Revision: 28-Jan-2021 **1** Document Number: 96545 For technical questions within your region: <u>DiodesAmericas@vishay.com</u>, <u>DiodesAsia@vishay.com</u>, <u>DiodesEurope@vishay.com</u>



www.vishay.com

Vishay Semiconductors

DYNAMIC RECOVERY CHARACTERISTICS (T _J = 25 °C unless otherwise specified)							
PARAMETER	SYMBOL	TEST CONDITIONS		MIN.	TYP.	MAX.	UNITS
		$I_F = 1.0 \text{ A}, dI_F/dt = 5$	0 A/μs, V _R = 30 V	-	33	=.	
Doverse receivery time		$I_F = 0.5 \text{ A}, I_R = 1 \text{ A}, I_{rr} = 0.25 \text{ A}$		-	-	23	
Reverse recovery time t _{rr}	Чrr	T _J = 25 °C		-	19	-	ns
		T _J = 125 °C		-	33	=.	
Dools woodstand outwork	l	T _J = 25 °C	I _F = 2 A dI _F /dt = 200 A/µs V _B = 100 V	-	1.7	=.	^
Peak recovery current I _{RRM}	IRRM	T _J = 125 °C		-	2.5	-	A
Reverse recovery charge Q _{rr}	0	T _J = 25 °C]	-	15	-	nC
	T _J = 125 °C		-	34	-	iiC	

THERMAL - MECHANICAL SPECIFICATIONS						
PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS
Maximum junction and storage temperature range	T _J , T _{Stg}		-55	-	175	°C
Thermal resistance, junction to mount	R _{thJM} ⁽¹⁾		-	16	20	
Thermal resistance, junction to ambient	R _{thJA}	Device mounted on FR4 PCB, 2 oz. standard footprint	-	160	-	°C/W
VS-1EQH01-M3		Case style MicroSMP (DO-219AD)	2H1			
Marking device VS-2EQH02-M3		Case style Microsivia (DO-219AD)	2H2			

Note

⁽¹⁾ Thermal resistance junction to mount follows JEDEC® 51-14 transient dual interface test method (TDIM)

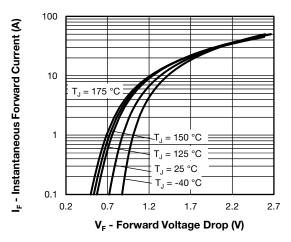


Fig. 1 - Typical Forward Voltage Drop Characteristics

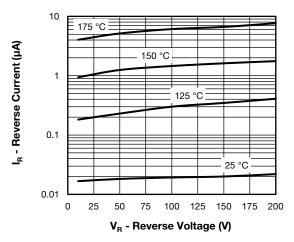


Fig. 2 - Typical Values of Reverse Current vs. Reverse Voltage

www.vishay.com Vishay Semiconductors

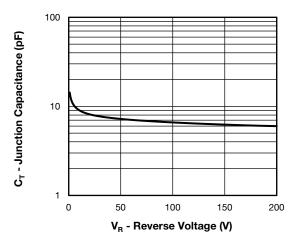


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage

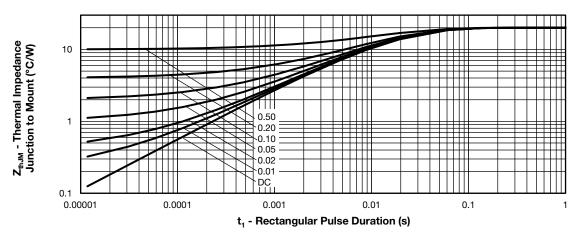


Fig. 4 - Maximum Transient Thermal Impedance, Junction to Mount

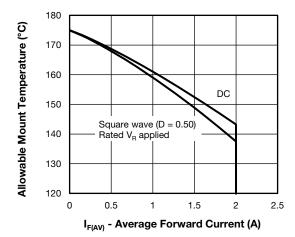


Fig. 5 - Maximum Allowable Mount Temperature vs. Average Forward Current

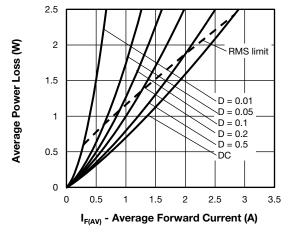


Fig. 6 - Forward Power Loss Characteristics

Note

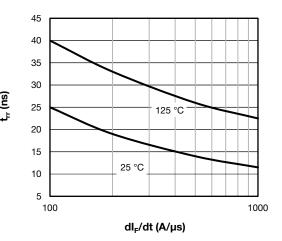
Formula used: $T_M = T_J$ - (Pd + Pd_{REV}) x R_{thJM}; Pd = forward power loss = $I_{F(AV)}$ x V_{FM} at ($I_{F(AV)}$ /D) (see fig. 5); Pd_{REV} = inverse power loss = V_{R1} x I_R (1 - D); I_R at V_{R1} = rated V_R

Revision: 28-Jan-2021 3 Document Number: 96545



VS-2EQH01-M3, VS-2EQH02-M3

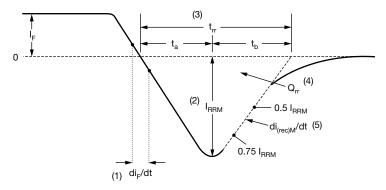
Vishay Semiconductors



50 45 125 °C 40 35 Q_{rr} (nC) 30 25 °C 25 20 15 10 5 100 1000 dl_F/dt (A/μs)

Fig. 7 - Typical Reverse Recovery Time vs. dl_F/dt

Fig. 8 - Typical Stored Charge vs. dl_F/dt



- (1) di_F/dt rate of change of current through zero crossing
- (2) I_{RRM} peak reverse recovery current
- (3) $\rm t_{rr}$ reverse recovery time measured from zero crossing point of negative going $\rm l_F$ to point where a line passing through 0.75 $\rm l_{RRM}$ and 0.50 $\rm l_{RRM}$ extrapolated to zero current.
- (4) \mathbf{Q}_{rr} area under curve defined by \mathbf{t}_{rr} and \mathbf{I}_{RRM}

$$Q_{rr} = \frac{t_{rr} \times I_{RRM}}{2}$$

(5) di_{(rec)M}/dt - peak rate of change of current during t_b portion of t_{rr}

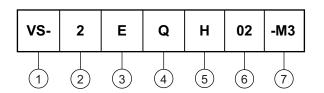
Fig. 9 - Reverse Recovery Waveform and Definitions

VS-2EQH01-M3, VS-2EQH02-M3

Vishay Semiconductors

ORDERING INFORMATION TABLE

Device code



1 - Vishay Semiconductors product

2 - Current rating (2 = 2 A)

3 - Circuit configuration:

E = single diode

4 - Q = MicroSMP package

5 - Process type,

H = ultrafast recovery

6 - Voltage code (02 = 200 V)

7 - -M3 = halogen-free, RoHS-compliant, and terminations lead (Pb)-free

ORDERING INFORMATION (Example)					
PREFERRED P/N	PREFERRED PACKAGE CODE	MINIMUM ORDER QUANTITY	PACKAGING DESCRIPTION		
VS-2EQH01-M3/H	Н	4500	7" diameter plastic tape and reel		
VS-2EQH02-M3/H	Н	4500	7" diameter plastic tape and reel		

LINKS TO RELATED DOCUMENTS				
Dimensions <u>www.vishay.com/doc?96591</u>				
Part marking information	www.vishay.com/doc?96590			
Packaging information	www.vishay.com/doc?88869			
SPICE model	www.vishay.com/doc?96595			

Revision: 28-Jan-2021 5 Document Number: 96545

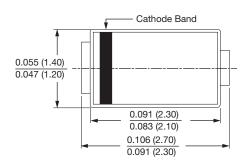


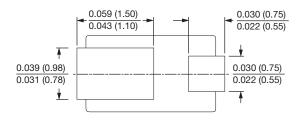


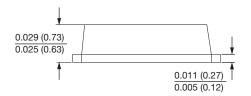
Vishay Semiconductors

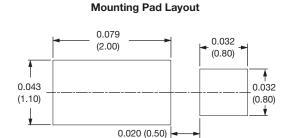
MicroSMP (DO-219AD), FRED Pt®

DIMENSIONS in inches (millimeters)









Legal Disclaimer Notice



Vishay

Disclaimer

ALL PRODUCT, PRODUCT SPECIFICATIONS AND DATA ARE SUBJECT TO CHANGE WITHOUT NOTICE TO IMPROVE RELIABILITY, FUNCTION OR DESIGN OR OTHERWISE.

Vishay Intertechnology, Inc., its affiliates, agents, and employees, and all persons acting on its or their behalf (collectively, "Vishay"), disclaim any and all liability for any errors, inaccuracies or incompleteness contained in any datasheet or in any other disclosure relating to any product.

Vishay makes no warranty, representation or guarantee regarding the suitability of the products for any particular purpose or the continuing production of any product. To the maximum extent permitted by applicable law, Vishay disclaims (i) any and all liability arising out of the application or use of any product, (ii) any and all liability, including without limitation special, consequential or incidental damages, and (iii) any and all implied warranties, including warranties of fitness for particular purpose, non-infringement and merchantability.

Statements regarding the suitability of products for certain types of applications are based on Vishay's knowledge of typical requirements that are often placed on Vishay products in generic applications. Such statements are not binding statements about the suitability of products for a particular application. It is the customer's responsibility to validate that a particular product with the properties described in the product specification is suitable for use in a particular application. Parameters provided in datasheets and / or specifications may vary in different applications and performance may vary over time. All operating parameters, including typical parameters, must be validated for each customer application by the customer's technical experts. Product specifications do not expand or otherwise modify Vishay's terms and conditions of purchase, including but not limited to the warranty expressed therein.

Hyperlinks included in this datasheet may direct users to third-party websites. These links are provided as a convenience and for informational purposes only. Inclusion of these hyperlinks does not constitute an endorsement or an approval by Vishay of any of the products, services or opinions of the corporation, organization or individual associated with the third-party website. Vishay disclaims any and all liability and bears no responsibility for the accuracy, legality or content of the third-party website or for that of subsequent links.

Except as expressly indicated in writing, Vishay products are not designed for use in medical, life-saving, or life-sustaining applications or for any other application in which the failure of the Vishay product could result in personal injury or death. Customers using or selling Vishay products not expressly indicated for use in such applications do so at their own risk. Please contact authorized Vishay personnel to obtain written terms and conditions regarding products designed for such applications.

No license, express or implied, by estoppel or otherwise, to any intellectual property rights is granted by this document or by any conduct of Vishay. Product names and markings noted herein may be trademarks of their respective owners.

© 2022 VISHAY INTERTECHNOLOGY, INC. ALL RIGHTS RESERVED